Silicon Epitaxial Planar Diode for Tuner Band Switch

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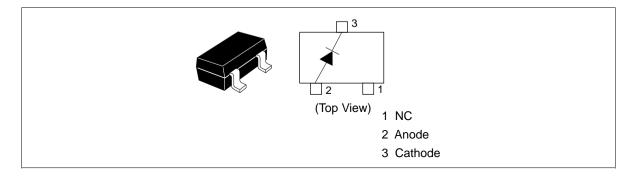
Features

- Low forward resistance. ($r_f = 0.9 \text{ max}$)
- Low capacitance. (C = 1.2pFmax)
- MPAK package is suitable for high density surface mounting and high speed assembly.

Ordering Information

| Type No. | Laser Mark | Package Code |
|----------|------------|--------------|
| HSM2692 | B1 | МРАК |

Pin Arrangement





Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

| Item | Symbol | Value | Unit |
|-----------------------|----------------|-------------|------|
| Reverse voltage | V _R | 35 | V |
| Power dissipation | Pd | 150 | mW |
| Junction temperature | Тј | 125 | °C |
| Storage temperature | Tstg | -45 to +125 | °C |
| Operation temperature | Topr | -20 to +60 | °C |

Electrical Characteristics (Ta = 25°C)

| Item | Symbol | Min | Тур | Мах | Unit | Test Condition |
|--------------------|----------------|-----|-----|-----|------|----------------------------------|
| Reverse voltage | V _R | 35 | _ | _ | V | $I_{R} = 10 \mu A$ |
| Reverse current | I _R | _ | — | 50 | nA | V _R = 25V |
| Forward voltage | V _F | _ | — | 1.0 | V | I _F = 10mA |
| Capacitance | С | _ | — | 1.2 | pF | $V_R = 6V, f = 1MHz$ |
| Forward resistance | r _f | | _ | 0.9 | Ω | I _F = 2mA, f = 100MHz |

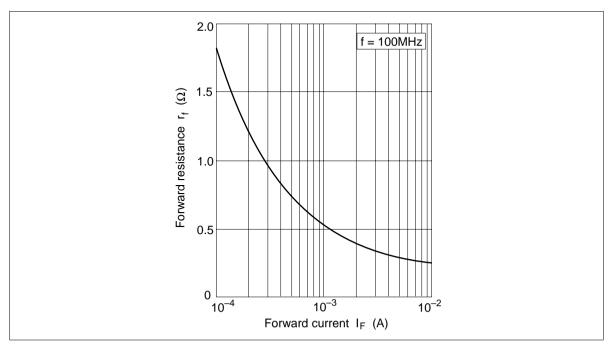


Fig.1 Forward resistance Vs. Forward current

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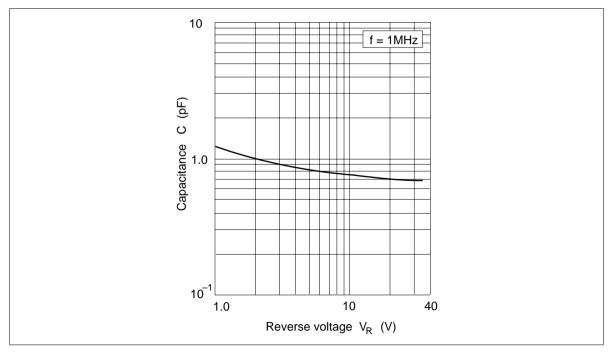


Fig.2 Capacitance Vs. Reverse voltage

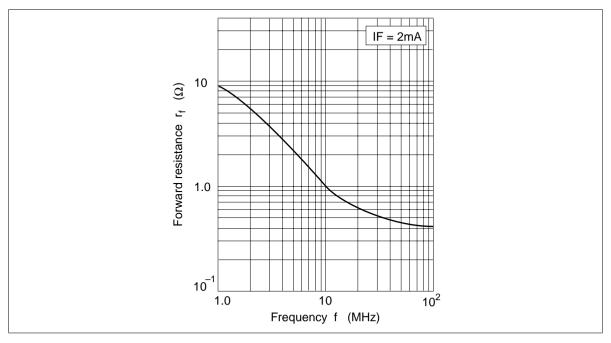
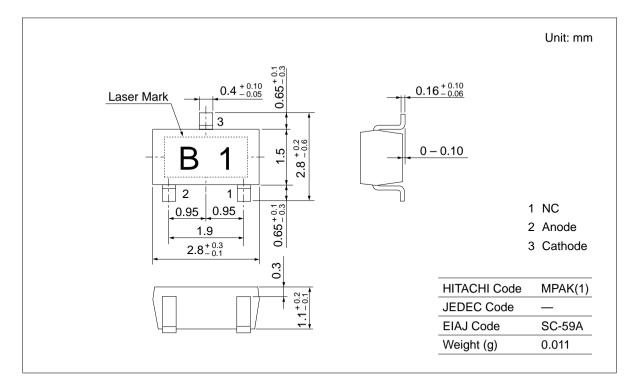


Fig.3 Forward resistance Vs. Frequency

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Package Dimensions



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